

## Phototriac chip OPTOTRIAC 130

### Description

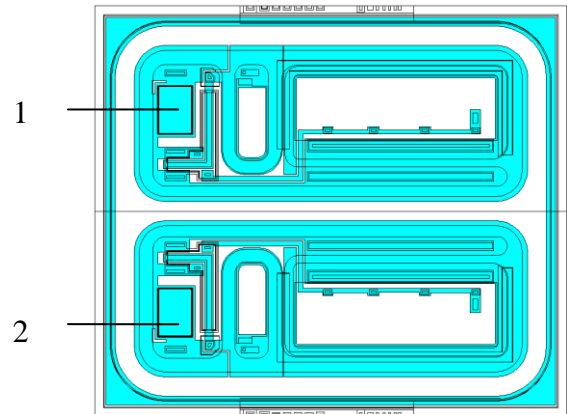
Zero voltage crossing-phototriac chip OPTOTRIAC 130 is designed to be used as phototriac receiver to drive power triacs in phototriacs and to switch AC-circuits in optoelectronic relays` circuits of consumer-oriented industrial automation.

### Features

- Chip size 1.5 x 1.3 mm
- Chip thickness  $0.36 \pm 0.02$  mm
- Contact pads size:  
Terminal 1, 2 - 0.108 mm x 0.152 mm
- Metallization: top - AlSi,  
bottom - Si

### Absolute maximum ratings

Storage Temperature	-65°C to 150°C
Operating Junction Temperature	-55°C to 125°C
Output Terminal Voltage	600 V



- 1 – Terminal 1  
2 – Terminal 2

### Electrical characteristics (T = 25 °C)

Parameter	Symbol	Min	Typ	Max	Units	Condition
Peak On-State Voltage	$V_{TM}$	-	1.6	2.0	V	$I_{TM} = \pm 100$ mA Note 1
Leakage Current in Inhibit State	$I_{IH}$	-	-	400	$\mu$ A	$V_{TM} = \pm 30$ V Note 1
Peak Off-State Current	$I_{DRM}$	-	-	1.0	$\mu$ A	$V_{DRM} = \pm 600$ V Note 2
Inhibit Voltage	$V_{IH}$	-	-	30	V	Note 1
Critical Rate of Rise Off-State Voltage	dv/dt	-	-	500	V/ $\mu$ s	Note 3

Notes:

- 1 – Light source with peak wavelength  $\lambda = 890 \pm 50$  nm that provides surface irradiance  $E_e = 20$  mW/cm<sup>2</sup> is used.  
2 – No light.  
3 – Measured in the packaged device.